

# CD4073B, CD4081B, CD4082B Types

## CMOS AND Gates

High-Voltage Types (20-Volt Rating)

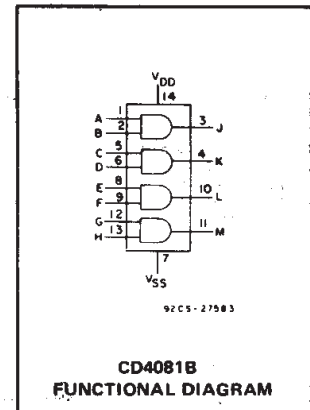
CD4073B Triple 3-Input AND Gate  
CD4081B Quad 2-Input AND Gate  
CD4082B Dual 4-Input AND Gate

■ CD4073B, CD4081B and CD-4082B AND gates provide the system designer with direct implementation of the AND function and supplement the existing family of CMOS gates.

The CD4073B, CD4081B, and CD4082B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

### Features:

- Medium-Speed Operation –  $t_{PLH}$ ,  $t_{PHL} = 60$  ns (typ.) at  $V_{DD} = 10$  V
- 100% tested for quiescent current at 20 V
- Maximum input current of  $1 \mu A$  at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =
  - 1 V at  $V_{DD} = 5$  V
  - 2 V at  $V_{DD} = 10$  V
  - 2.5 V at  $V_{DD} = 15$  V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



### MAXIMUM RATINGS, Absolute-Maximum Values:

#### DC SUPPLY-VOLTAGE RANGE, ( $V_{DD}$ )

Voltages referenced to  $V_{SS}$  Terminal) ..... -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to  $V_{DD} + 0.5V$

DC INPUT CURRENT, ANY ONE INPUT .....  $\pm 10$  mA

#### POWER DISSIPATION PER PACKAGE ( $P_D$ ):

For  $T_A = -55^\circ C$  to  $+100^\circ C$  ..... 500mW

For  $T_A = +100^\circ C$  to  $+125^\circ C$  ..... Derate Linearly at 12mW/ $^\circ C$  to 200mW

#### DEVICE DISSIPATION PER OUTPUT TRANSISTOR

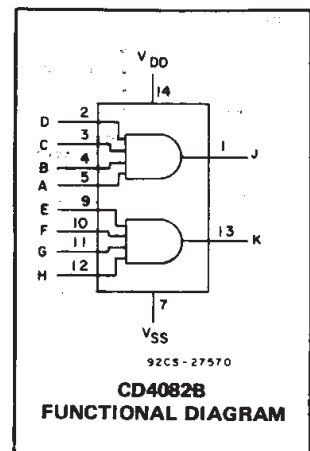
FOR  $T_A =$  FULL PACKAGE-TEMPERATURE RANGE (All Package Types) ..... 100mW

OPERATING-TEMPERATURE RANGE ( $T_A$ ) .....  $-55^\circ C$  to  $+125^\circ C$

STORAGE TEMPERATURE RANGE ( $T_{stg}$ ) .....  $-65^\circ C$  to  $+150^\circ C$

#### LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16  $\pm$  1/32 inch (1.59  $\pm$  0.79mm) from case for 10s max .....  $+265^\circ C$



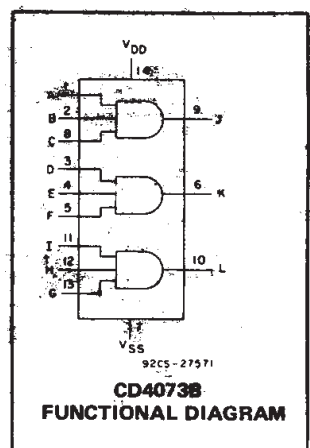
### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For $T_A =$ Full Package Temperature Range)	3	18	V

DYNAMIC ELECTRICAL CHARACTERISTICS at  $T_A = 25^\circ C$ , Input  $t_r, t_f = 20$  ns, and  $C_L = 50$  pF,  $R_L = 200$  k $\Omega$

CHARACTERISTIC	TEST CONDITIONS	ALL TYPES LIMITS			UNITS
		V <sub>DD</sub> Volts	TYP.	MAX.	
Propagation Delay Time, t <sub>PHL</sub> , t <sub>PLH</sub>		5	125	250	ns
		10	60	120	
		15	45	90	
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>		5	100	200	ns
		10	50	100	
		15	40	80	
Input Capacitance, C <sub>IN</sub>	Any Input	—	5	7.5	pF



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## STATIC ELECTRICAL CHARACTERISTICS

CHARACTER- ISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V <sub>O</sub> (V)	V <sub>IN</sub> (V)	V <sub>DD</sub> (V)					+25			
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I <sub>DD</sub> Max.	—	0,5	5	0.25	0.25	7.5	7.5	—	0.01	0.25	μA
	—	0,10	10	0.5	0.5	15	15	—	0.01	0.5	
	—	0,15	15	1	1	30	30	—	0.01	1	
	—	0,20	20	5	5	150	150	—	0.02	5	
Output Low (Sink) Current I <sub>OL</sub> Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I <sub>OH</sub> Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V <sub>OL</sub> Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V <sub>OH</sub> Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V <sub>IL</sub> Max.	0.5	—	5	1.5				—	—	1.5	V
	1	—	10	3				—	—	3	
	1.5	—	15	4				—	—	4	
Input High Voltage, V <sub>IH</sub> Min.	0.5,4.5	—	5	3.5				3.5	—	—	V
	1,9	—	10	7				7	—	—	
	1.5,13.5	—	15	11				11	—	—	
Input Current I <sub>IN</sub> Max.		0,18	18	±0.1	±0.1	±1	±1	—	±10 <sup>-5</sup>	±0.1	μA

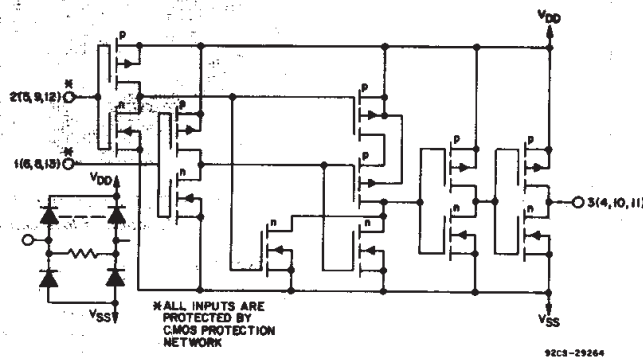


Fig. 1 — Schematic diagram for CD4081B (1 of 4 identical gates).

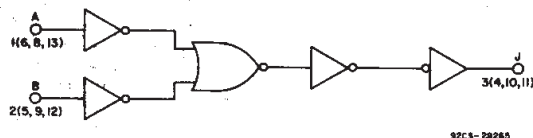


Fig. 2 — Logic diagram for CD4081B (1 of 4 identical gates).

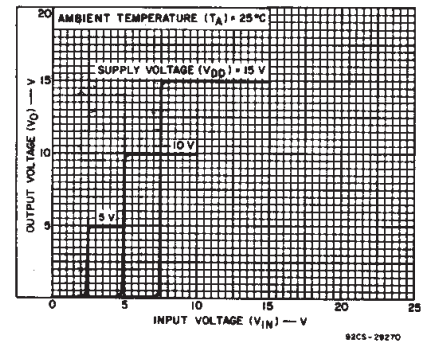


Fig. 3 — Typical voltage transfer characteristics.

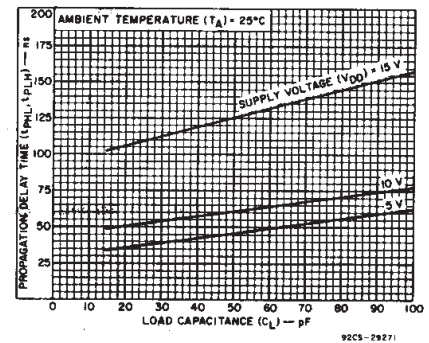


Fig. 4 — Typical propagation delay time as a function of load capacitance.

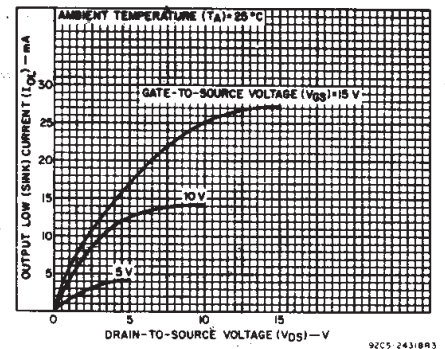


Fig. 5 — Typical output low (sink) current characteristics.

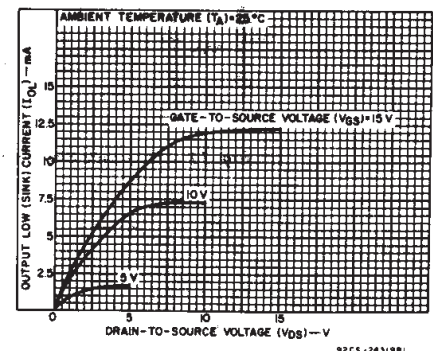


Fig. 6 — Minimum output low (sink) current characteristics.